

# **Data Sheet**

## **Description/Application**

Avago Technologies's HSMP-386Z is a General Purpose PIN Diode housed in a low cost surface mount SOD-323 package. This package offers customers who already use the PIN Diode in SOT-23 and SOT-323 packages, a logical transition to a smaller package outline to accommodate end product design with limited board space.

The HSMP-386Z is designed for two classes of applications. The first is attenuator where current consumption is the most important design consideration. The second application is switches where low capacitance is the driving issue for the designer.

A SPICE model is not available for PIN diodes as SPICE does not provide for a key PIN diode characteristic -- carrier lifetime.

#### **Package Marking and Pin Connections**



Note:

Package marking provides orientation and identification

"C" = Device Code

"?" = Month code indicates the month of manufacture

#### Features

- 2 Leads Surface Mount Package
- Switching
  - Low Distortion Switching - Low Capacitance
- Attenuating
  Low Current Attenuating for Less Particular
  - Low Current Attenuating for Less Power Consumption
- MSL 1 & Lead Free
- Tape and Reel Options Available
- Low Failure in Time (FIT) Rate

Symbol	Parameter	Unit	Max Rating
lf	Forward Current (1 µs Pulse)	Amp	1
P <sub>IV</sub>	Peak Inverse Voltage	V	100
T <sub>j</sub>	Junction Temperature	٥C	150
T <sub>stg</sub>	Storage Temperature	٥C	-60 to 150
θ <sub>jb</sub>	Thermal Resistance <sup>[2]</sup>	⁰C/W	135

#### Table 1. Absolute Maximum Ratings [1] at $Tc = +25^{\circ}C$

Notes:

1. Operation in excess of any one of these conditions may result in permanent damage to the device.

2. Thermal Resistance is measured from junction to board using IR method.

## Table 2. Electrical Specifications at $Tc = +25^{\circ}C$

	Minimum Breakdown Voltage V <sub>BR</sub> (V)	Typical Total Resistance R <sub>s</sub> (Ohm)	Typical Total Capacitance $\textbf{C}_{\tau}$ (pF)
	50	3.0/1.5*	0.20
Test Conditions	$V_{R} = V_{BR}$ Measure $I_{R} \le 10$ uA	I <sub>F</sub> = 10mA/100mA* f = 100 MHz	$V_{R} = 50V$ f = 1MHz

#### Table 3. Typical Parameters at $Tc = +25^{\circ}C$

	Series Resistance RS (Ohm)	Carrier Lifetime $ au$ (ns)	Reverse Recovery Time T <sub>rr</sub> (ns)	Total Capacitance C⊤ (pF)
	22	500	80	0.20
Test Conditions	$I_F = 1 \text{ mA}$ f = 100 MHz	I <sub>F</sub> = 50mA I <sub>R</sub> = 250mA	V <sub>R</sub> = 10V I <sub>F</sub> = 20mA 90% Recovery	$V_{R} = 50V$ f = 1MHz

## Typical Performance Curves at $Tc = +25^{\circ}C$











Figure 5. Typical Reverse Recovery Time vs. Reverse Voltage



Figure 2. Forward Current vs. Forward Voltage



Figure 4. 2nd Harmonic Input Intercept Point vs. Diode RF Resistance

## **Package Outline and Dimension**





## **PCB Footprint**



Dimension in mm



DIM	MILLIMETERS	
Α	2.50 ±0.2	
В	1.25 ±0.05	
С	0.90 ±0.05	
D	0.30+0.06/-0.04	
E	1.70 ±0.05	
F	MIN 0.17	
G	0.126 ±0.03	
Н	0~0.1	
I	1.0 MAX	
J	0.15 ±0.05	
К	0.4	
L	2°+4/-2	
M4	~6°	

# **Device Orientation**



## **Tape Dimensions**





A - A' SECTION

Specification < Unit: mm >

A. hole pitch : 50 Pitch Tolerance : 200  $\pm$  0.3

## **Part Number Ordering Information**

Part number	No. of Units	Container
HSMP-386Z-BLKG	100	Anti-static bag
HSMP-386Z-TR1G	3000	7" reel

For product information and a complete list of distributors, please go to our web site: www

www.avagotech.com

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